

DS16F95QML EIA-485/EIA-422A Differential Bus Transceiver

Check for Samples: DS16F95QML

FEATURES

- Radiation Guaranteed 300 krad(Si)
- Meets EIA-485 and EIA-422A
- Meets SCSI-1 (5 MHZ) Specifications
- Designed for Multipoint Transmission
- Wide Positive and Negative Input/Output Bus Voltage Ranges
- Thermal Shutdown Protection
- Driver Positive and Negative Current-Limiting
- High Impedance Receiver Input
- Receiver Input Hysteresis of 50 mV Typical
- Operates from Single 5.0V Supply
- Reduced Power Consumption
- Pin Compatible with DS3695 and SN75176A

DESCRIPTION

The DS16F95 Differential Bus Transceiver is a monolithic integrated circuit designed for bidirectional data communication on balanced multipoint bus transmission lines. The transceiver meets EIA standard RS-485 as well as RS-422A.

The DS16F95 offers improved performance due to the use of state-of-the-art L-FAST bipolar technology. The L-FAST technology allows for higher speeds and lower currents by utilizing extremely short gate delay times. Thus, the DS16F95QML features lower power, extended temperature range and improved specifications.

The DS16F95 combines a TRI-STATE differential line driver and a differential input line receiver, both of which operate from a single 5.0V power supply. The driver and receiver have an active Enable that can be externally connected to function as a direction control. The driver differential outputs and the receiver differential inputs are internally connected to form differential input/output (I/O) bus ports that are designed to offer minimum loading to the bus whenever the driver is disabled or when $V_{CC} = 0V$. These ports feature wide positive and negative common mode voltage ranges, making the device suitable for multipoint applications in noisy environments.

The driver is designed to accommodate loads of up to 60 mA of sink or source current and features positive and negative current limiting in addition to thermal shutdown for protection from line fault conditions.

The DS16F95 can be used in transmission line applications employing the DS96F172 and the DS96F174 quad differential line drivers and the DS96F173 and DS96F175 quad differential line receivers.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



Connection Diagram

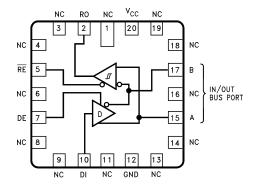


Figure 1. 20-Lead Ceramic Leadless Chip Carrier

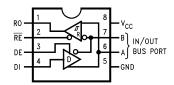


Figure 2. 8-Lead Dual-In-Line Package

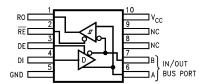


Figure 3. 10-Lead Flatpak Package

Logic Diagram

Function Tables

Table 1. Driver⁽¹⁾

Driver Input	Enable	Outputs			
DI	DE	Α	В		
Н	Н	Н	L		
L	Н	L	Н		
X	L	Z	Z		

(1) H = High Level, L = Low Level, X = Immaterial, Z = High Impedance (Off)



Table 2. Receiver⁽¹⁾

Differential Inputs	Inputs Enable		
A-B	RE	RO	
V _{ID} ≥ 0.2V	L	Н	
V _{ID} ≤ -0.2V	L	L	
Х	Н	Z	

(1) H = High Level, L = Low Level, X = Immaterial, Z = High Impedance (Off)



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings(1)

Storage Temperature Range			-65°C ≤ T _A ≤ $+175$ °C
Lead Temperature	(Soldering, 60 sec.)		300°C
	LCCC 'NAJ' Package		1800 mW
Maximum Power Dissipation at 25°C (2)	CDIP 'NAB' Package		1274 mW
	CLGA 'NAD' Package		725 mW
Supply Voltage			7.0V
Input Voltage (Bus Terminal)			+15V/-10V
Enable Input Voltage			5.5V
Junction Temperature (TJ)			+175°C
		LCCC 'NAJ' Package	83°C/W @ 0.5W
	θ_{JA}	CDIP 'NAB' Package	118°C/W @ 1.0W
Thermal Resistance		CLGA 'NAD' Package	207°C/W @ 0.5W
mermai Resistance		LCCC 'NAJ' Package	17°C/W
	θ_{JC}	CDIP 'NAB' Package	14°C/W
	CLGA 'NAD' Package		18°C/W
ESD Tolerance ⁽³⁾			500V

^{(1) &}quot;Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" provide conditions for actual device operation.

Recommended Operating Conditions

	4.50 to 5.50V
(Separately or Common Mode) (V _I or V _{CM})	-7.0V to +12V
	-7.0V to ±12V
Driver	-60mA
Receiver	-400µA
Driver	60mA
Receiver	16mA
	-55°C to +125°C
	(Separately or Common Mode) (V _I or V _{CM}) Driver Receiver Driver

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⁽²⁾ Ábove T_A = 25°C, derate NAJ package 12.1mW°C, NAB package 8.5 mW/°C, NAD package 4.8mW/°C.

⁽³⁾ Human body model, 1.5kΩ in series with 100pF



Quality Conformance Inspection

MIL-STD-883, Method 5005 - Group A

Subgroup	Description	Temp (°C)
1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

DC - Driver Electrical Characteristics(1)

The following conditions apply to all parameters, unless otherwise specified. $V_{CC} = 5.5V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
VOD1	Differential Manual	$V_{CC} = 5.5V, I_O = 0A, V_{IN} = .8V$			6	V	1, 2, 3
VODT	Differential Vout	$V_{CC} = 5.5V$, $I_{O} = 0A$, $V_{IN} = 2V$			6	V	1, 2, 3
VOD2	Differential Vout (See Figure 4)	$V_{CC} = 4.5V, R_L = 100\Omega$		2		V	1, 2, 3
VODZ	Differential Vout (See Figure 4)	V_{CC} = 4.5V, R_L = 54 Ω		1.5		V	1, 2, 3
A\/	Change In Differential Vaut	$V_{CC} = 4.5V, R_{L} = 100\Omega$	See ⁽²⁾	-200	200	mV	1, 2, 3
ΔV_{OD}	Change In Differential Vout	V_{CC} = 4.5V, R_L = 54 Ω	See	-200	200	mV	1, 2, 3
A \/	Change In Common Mode Vout	$V_{CC} = 4.5V, R_L = 100\Omega$	See ⁽²⁾	-200	200	mV	1, 2, 3
ΔV _{OC}		V_{CC} = 4.5V, R_L = 54 Ω	See. /	-200	200	mV	1, 2, 3
V		$R_L = 100\Omega$			3	V	1, 2, 3
V _{oc}	Common Mode Vout	$R_L = 54\Omega$			3	V	1, 2, 3
I _{IH}	Logical "1" Input Current	$V_1 = 2.4V$			20	uA	1, 2, 3
		Output Disable, V _O = 12V			1	mA	1, 2, 3
	Output Current	Output Disable, $V_O = -7V$	See ⁽³⁾	-0.8		mA	1, 2, 3
Io	Output Current	$V_{CC} = 0$, Output Disable, $V_{O} = 12V$			1	mA	1, 2, 3
		$V_{CC} = 0$, Output Disable, $V_{O} = -7V$	See ⁽³⁾	-0.8		mA	1, 2, 3

⁽¹⁾ Pre and post irradiation limits are identical to those listed under A C and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in MIL-STD 883, Method 1019, condition A.

⁽²⁾ $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level.

⁽³⁾ Negative sign of the limits indicates the direction of the current flow only.



DC - Driver Electrical Characteristics⁽¹⁾ (continued)

The following conditions apply to all parameters, unless otherwise specified. $V_{CC} = 5.5V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
		$V_{IN} = 3V$, $V_{OUT} = V_{CC}$			150	mA	1, 2, 3
		$V_{IN} = 3V$, $V_{OUT} = -7V$	See ⁽⁴⁾	-250		mA	1, 2, 3
		$V_{IN} = 3V$, $V_{OUT} = 0V$	See	-150		mA	1, 2, 3
	Output Short Circuit	V _{IN} = 3V, V _{OUT} = 12V			250	mA	1, 2, 3
I _{OS}	Output Short Circuit	$V_{IN} = 0V$, $V_{OUT} = 12V$			250	mA	1, 2, 3
		$V_{IN} = 0V$, $V_{OUT} = V_{CC}$			150	mA	1, 2, 3
		$V_{IN} = 0V$, $V_{OUT} = -7V$	See ⁽⁴⁾	-250		mA	1, 2, 3
		$V_{IN} = 0V, V_{OUT} = 0V$	See	-150		mA	1, 2, 3
V _{OH}	Logical "1" Output Voltage	$V_{CC} = 4.5V, I_{O} = -20mA$		3		V	1, 2, 3
V _{OL}	Logical "0" Output Voltage	$V_{CC} = 4.5V, I_{O} = 20mA$			2	V	1, 2, 3
VOD3	Differential Vout	V _{CM} = -7V to 12V		1		V	1, 2, 3

⁽⁴⁾ Negative sign of the limits indicates the direction of the current flow only.

DC - Receiver Electrical Characteristics(1)

The following conditions apply to all parameters, unless otherwise specified. $V_{CC} = 5.5V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
V _{OH}	Logical "1" Output Voltage (See Figure 5)	$V_{CC} = 4.5V, V_{LD} = 200 \text{mV},$ $I_{OH} = -400 \text{uA}$		2.5		V	1, 2, 3
V	Logical "0" Output Voltage	V_{CC} = 4.5V, V_{LD} = -200mV, I_{OL} = 8mA			.45	V	1, 2, 3
V _{OL}	(See Figure 5)	$V_{CC} = 4.5V, V_{LD} = -200 \text{mV},$ $I_{OL} = 16 \text{mA}$.5	V	1, 2, 3
		Untested Input = 0V, V _I = 12V			1	mA	1, 2, 3
		Untested Input = 0V, V _I = -7V	See ⁽²⁾	8		mA	1, 2, 3
l _l	Line Input Current	V _{CC} = 0V, Untested Input = 0V, V _I = 12V	See ⁽²⁾		1	mA	1, 2, 3
		$V_{CC} = 0V$, Untested Input = 0V, $V_{I} = -7V$		8		mA	1, 2, 3
I _{IH}	Logical "1" Input Current	V _I = 2.7V (Receiver)			20	uA	1, 2, 3
		Untested Input = 0V, V _I = 12V	See ⁽³⁾	10		ΚΩ	1, 2, 3
		Untested Input = 0V, V _I = -7V	See	10		ΚΩ	1, 2, 3
R _{IN}	Input Resistance	$V_{CC} = 0V$, Untested Input = 0V, $V_1 = 12V$	See ⁽³⁾	10		ΚΩ	1, 2, 3
		$V_{CC} = 0V$, Untested Input = $0V$, $V_{I} = -7V$	See	10		ΚΩ	1, 2, 3
	Lligh Impedance State	V _I = 0.4V		-20	20	uA	1, 2, 3
I_{OZ}	High Impedance State	V _I = 2.4V		-20	20	uA	1, 2, 3

⁽¹⁾ Pre and post irradiation limits are identical to those listed under A C and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in MIL-STD 883, Method 1019, condition A.

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Negative sign of the limits indicates the direction of the current flow only.

⁽³⁾ R_{IN} is guaranteed by testing "Line Input Current" (II).



DC - Receiver Electrical Characteristics⁽¹⁾ (continued)

The following conditions apply to all parameters, unless otherwise specified. $V_{CC} = 5.5V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
los	Output Short Circuit	V _{IN} = 1V, V _{OUT} = 0V		-85	-15	mA	1, 2, 3
V	Differential Input High	$V_{CC} = 4.5V, V_O = 2.5V,$ $V_{CM} = 12V \& 0V \& -7V, I_O =4mA$.2	V	1, 2, 3
V_{TH}	Threshold Threshold	V _{CC} = 5.5V, Vo = 2.5V, V _{CM} = 12V & 0V & -7V, I _O =4mA			.2	V	1, 2, 3
V/ 4	Differential Input Low	$V_{CC} = 4.5V, V_{O} = .5V, V_{CM} = 12V & 0V & -7V, I_{O} = 8mA$		2		V	1, 2, 3
V _T 1 Threshold	Threshold	$V_{CC} = 5.5V, V_{O} = .5V, V_{CM} = 12V & 0V & -7V, I_{O} = 8mA$		2		V	1, 2, 3
V _{TH} +		$V_{CC} = 4.5V, V_{CM} = 0V$		35		mV	1, 2, 3
- (V _{TH} -)		$V_{CC} = 5.5V, V_{CM} = 0V$		35		mV	1, 2, 3

DC - Both Driver and Receiver Electrical Characteristics(1)

The following conditions apply to all parameters, unless otherwise specified. $V_{CC} = 5.5V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
I _{CC}	Supply Current I _{CC} Both Disable	$\overline{RE} = 2V, \overline{DE} = .8V$			25	mA	1, 2, 3
I _{CC}	Supply Current I _{CC} Both Enable	\overline{RE} =.8V, \overline{DE} = 2V			28	mA	1, 2, 3
V _{IC}	Input Clamp Volt	I _I = -18mA		-1.3		V	1, 2, 3
V_{IH}	Logical "1" Input Voltage			2		V	1, 2, 3
V_{IL}	Logical "0" Input Voltage				.8	V	1, 2, 3
V _{IH}	Logical "1" Enable Input Voltage			2		V	1, 2, 3
V _{IL}	Logical "0" Enable Input Voltage				.8	V	1, 2, 3
LIL	Logical "0" Input Current	$V_{I} = 0.4V$	See (2)	-50		uA	1, 2, 3

⁽¹⁾ Pre and post irradiation limits are identical to those listed under A C and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in MIL-STD 883, Method 1019, condition A.

(2) Negative sign of the limits indicates the direction of the current flow only.

AC - Driver Electrical Characteristics(1)

The following conditions apply to all parameters, unless otherwise specified.

 $V_{CC} = 5V$, PRR = 1MH_Z, $T_R \le T_F \le 6nS$, 50% duty cycle, AMP = 3V, VL_O , $Z_{OUT} = 50\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
t _{DD}	Differential Output Delay Time	B - 600	See (2)	8	25	nS	9
	(See Figure 6)	$R_L = 60\Omega$	See · /	8	30	nS	10, 11
	Differential Output Transition	B - 600	See ⁽²⁾⁽³⁾	8	25	nS	9
t _{TD}	Time (See Figure 6) $R_L = 60\Omega$ $See^{(2)(3)}$	8	30	nS	10, 11		
	Propagation Delay Time Low to High (See Figure 7)	$R_L = 27\Omega$		6	18	nS	9
t _{PLH}				6	25	nS	10, 11
	Propagation Delay Time high to	D 070		6	18	nS	9
t _{PHL}	Low (See Figure 7)	$R_L = 27\Omega$		6	25	nS	10, 11
	Output Enable Time to H	B = 1100			35	nS	9
t _{PZH}	(See Figure 8)	$R_L = 110\Omega$			45	nS	10, 11
	Output Enable Time to L	D 4400			40	nS	9
t _{PZL}	(See Figure 9)	$R_L = 110\Omega$			50	nS	10, 11

⁽¹⁾ Pre and post irradiation limits are identical to those listed under A C and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in MIL-STD 883, Method 1019, condition A.

⁽²⁾ Rise time 20% to 80%, Fall time 80% to 20%.

⁽³⁾ tTD = Non-inverting output rise time + inverting output fall time / 2, Non-inverting output fall time + inverting output rise time / 2.



AC - Driver Electrical Characteristics(1) (continued)

The following conditions apply to all parameters, unless otherwise specified.

 V_{CC} = 5V, PRR = 1MH_Z, $T_R \le T_F \le$ 6nS, 50% duty cycle, AMP = 3V, VL_O, Z_{OUT} = 50 Ω

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
t _{PHZ} Output Disable (See Figure 8)	Output Disable Time to H	RL = 110Ω			30	nS	9
	(See Figure 8)	$RL = 110\Omega$			40	nS	10, 11
	Output Disable Time to L	$R_L = 110\Omega$			30	nS	9
t _{PLZ}	(See Figure 9)				40	nS	10, 11
т	Differential Output Skew Time (See Figure 6)				6	nS	9
T _{SKEW}					12	nS	10, 11

AC - Receiver Electrical Characteristics(1)

The following conditions apply to all parameters, unless otherwise specified.

 $V_{CC} = 5V$, PRR = 1MH_z, $T_R \le T_F \le 6$ nS, 50% duty cycle, AMP = 3V, VL_O, $Z_{OUT} = 50\Omega$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub-group
t _{PLH}	Propagation Delay Time Low to	C _L = 15pF		10	27	nS	9
PLH	High (See Figure 10)	SL = 10pi		10	38	nS	10, 11
t _{PHL}	Propagation Delay Time High to	$C_1 = 15pF$		10	27	nS	9
	Low (See Figure 10)	CL = 15pr		10	38	nS	10, 11
t _{PZH}	Output Enable Time to H	$C_1 = 15pF$			20	nS	9
	(See Figure 11)	CL = 15pr			30	nS	10, 11
t _{PZL}	Output Enable Time to L	$C_1 = 15pF$			20	nS	9
	(See Figure 11)	C _L = 15pr			30	nS	10, 11
t _{PLH} - t _{PHL}	Output to Output Delay Time				8	nS	9
	(See Figure 10)				16	nS	10, 11
t _{PHZ}		C 20°E	See ⁽²⁾		30	nS	9
	Output Disable Time From H (See Figure 11)	$C_L = 20pF$	See (=)		40	nS	10, 11
		0 5-5	See ⁽²⁾		20	nS	9
		$C_L = 5pF$	See (=)		30	nS	10, 11
t _{PLZ}	Output Disable Time From L	C 525			20	nS	9
	(See Figure 11)	$C_L = 5pF$			30	nS	10, 11

⁽¹⁾ Pre and post irradiation limits are identical to those listed under A C and DC electrical characteristics. These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in MIL-STD 883, Method 1019, condition A.

(2) Testing at 20pF assures conformance to spec at 5pF.



Parameter Measurement Information

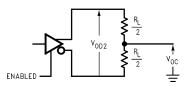


Figure 4. Driver V_{OD} and V_{OC}⁽¹⁾

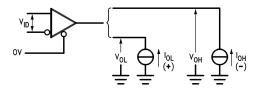
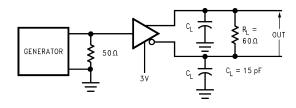
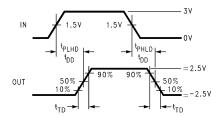


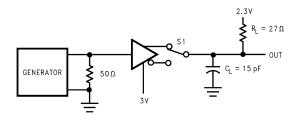
Figure 5. Receiver V_{OH} and V_{OL}





 $t_{SKEW} = |t_{PLHD} - t_{PHLD}|$

Figure 6. Driver Differential Output Delay and Transition Times⁽²⁾⁽³⁾



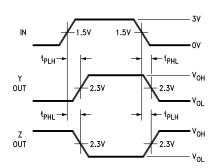
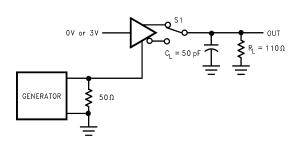


Figure 7. Driver Propagation Times⁽²⁾⁽⁴⁾



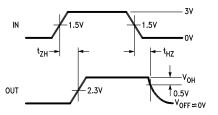


Figure 8. Driver Enable and Disable Times $(t_{ZH}, t_{HZ})^{(2)(3)(4)}$

- (1) All diodes are 1N916 or equivalent.
- (2) The input pulse is supplied by a generator having the following characteristics: PRR = 1.0 MHz, 50% duty cycle, $t_r \le 6.0$ ns, $t_f \le 6.0$ ns, $Z_0 = 50\Omega$.
- (3) DS16F95 Driver enable is Active-High.
- (4) C_L includes probe and stray capacitance.



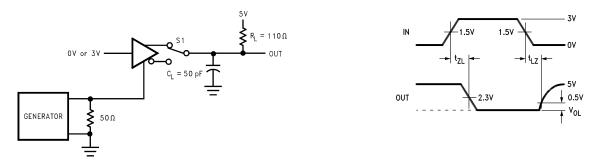


Figure 9. Driver Enable and Disable Times $(t_{ZL}, t_{LZ})^{(1)(2)(3)}$

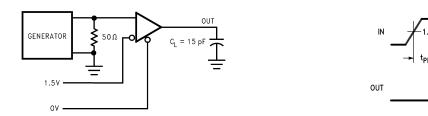
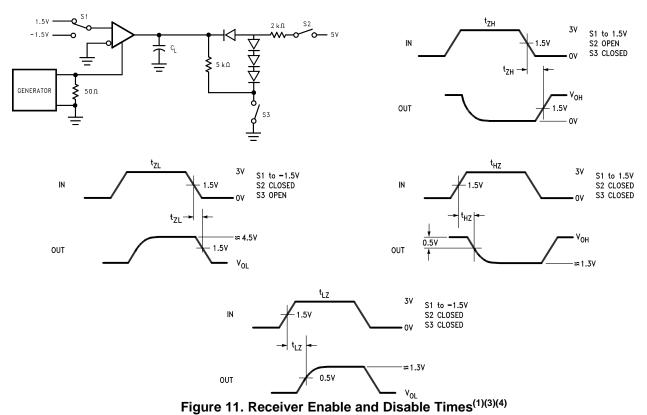


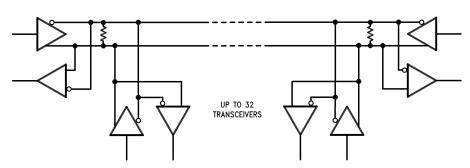
Figure 10. Receiver Propagation Delay Times⁽¹⁾⁽³⁾



- (1) The input pulse is supplied by a generator having the following characteristics: PRR = 1.0 MHz, 50% duty cycle, t_r ≤ 6.0 ns, t_f ≤ 6.0 ns, Z_O = 50Ω.
- (2) DS16F95 Driver enable is Active-High.
- (3) C_L includes probe and stray capacitance.
- (4) All diodes are 1N916 or equivalent.



Typical Application



The line should be terminated at both ends in its characteristic impedance, typically 120Ω . Stub lengths off the main line should be kept as short as possible.



REVISION HISTORY

Date Released	Revision	Section	Changes			
9/23/2005	А	New Release, Corporate format	1 MDS data sheet converted into Corporate data sheet format. MDS data sheet MNDS16F95-X-RH, Rev. 0A1 will be Archived.			
10/26/2010	В	Features, Ordering Table, Connection Diagrams W pkg, Absolute Ratings, Electricals - DC Receiver V _T 1, AC Driver conditions, Physical Dimensions Mkt drawing	Update with current device information and format. Correction to rad info., Code K NSID's removed, removed reference to WG pkg, typo correction to conditions, Removed WG pkg drawing. Revision A will be Archived			

Product Folder Links: DS16F95QML



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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
5962-89615012A	ACTIVE	LCCC	NAJ	20	50	TBD	POST-PLATE	Level-1-NA-UNLIM	-55 to 125	DS16F95E /883 Q 5962-89615 012A ACO 012A >T	Samples
5962-8961501PA	ACTIVE	CDIP	NAB	8	40	TBD	A42 SNPB	Level-1-NA-UNLIM	-55 to 125	DS16F95J/883 5962-89615 01PA Q ACO 01PA Q >T	Samples
5962F8961501VHA	ACTIVE	CLGA	NAD	10	19	TBD	A42 SNPB	Level-1-NA-UNLIM	-55 to 125	DS16F95 WFQMLV Q 5962F89615 01VHA ACO 01VHA >T	Samples
DS16F95E/883	ACTIVE	LCCC	NAJ	20	50	TBD	POST-PLATE	Level-1-NA-UNLIM	-55 to 125	DS16F95E /883 Q 5962-89615 012A ACO 012A >T	Samples
DS16F95J/883	ACTIVE	CDIP	NAB	8	40	TBD	A42 SNPB	Level-1-NA-UNLIM	-55 to 125	DS16F95J/883 5962-89615 01PA Q ACO 01PA Q >T	Samples
DS16F95W/883	ACTIVE	CLGA	NAD	10	19	TBD	A42 SNPB	Level-1-NA-UNLIM	-55 to 125	DS16F95W /883 Q ACO /883 Q >T	Samples
DS16F95WFQMLV	ACTIVE	CLGA	NAD	10	19	TBD	A42 SNPB	Level-1-NA-UNLIM	-55 to 125	DS16F95 WFQMLV Q 5962F89615 01VHA ACO 01VHA >T	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

PACKAGE OPTION ADDENDUM



www.ti.com 24-Jan-2013

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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OTHER QUALIFIED VERSIONS OF DS16F95QML, DS16F95QML-SP:

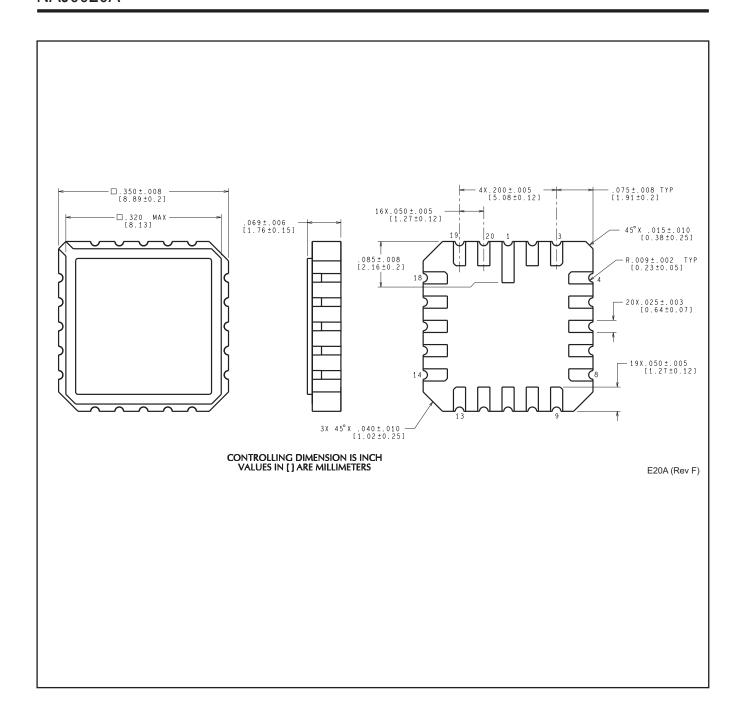
Military: DS16F95QML

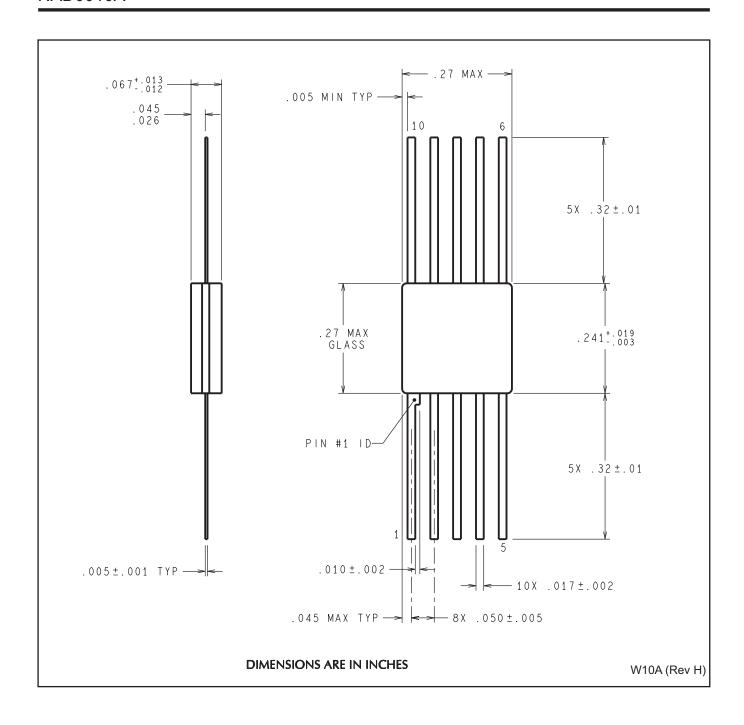
Space: DS16F95QML-SP

NOTE: Qualified Version Definitions:

- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application









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